













CSD87313DMS

SLPS642 - APRIL 2017

CSD87313DMS 30-V Dual N-Channel NexFET™ Power MOSFETs

Features

- Low-Source-to-Source On Resistance
- **Dual Common Drain N-Channel MOSFETs**
- Optimized for 5-V Gate Drive
- Low Q_q and Q_{qd}
- Low-Thermal Resistance
- Avalanche Rated
- Lead-Free Terminal Plating
- **RoHS Compliant**
- Halogen Free
- SON 3.3-mm × 3.3-mm Plastic Package

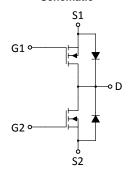
Applications

- USB Type-C™ and Power Delivery (PD) VBus Protection
- **Battery Protection**
- Load Switch

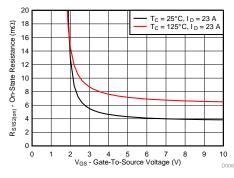
3 Description

The CSD87313DMS is a 30-V common drain, dual Nchannel device designed for USB Type-C/PD and battery protection. This SON 3.3-mm x 3.3-mm device has low-source-to-source on resistance that minimizes losses and offers low-component count for space constrained applications.





R_{S1S2(ON)} vs V_{GS}



Product Summary

$T_A = 25^{\circ}C$		VALUE	UNIT		
V _{S1S2}	Source1-to-Source2 Voltage	30	٧		
Q_g	Gate Charge Total (4.5 V) 28				
Q_{gd}	Gate Charge Gate-to-Drain 6.0				
D	Max Source1-to-Source2 On	V _{GS} = 2.5 V	9.6	mΩ	
R _{S1S2(on)}	Resistance	$V_{GS} = 4.5 \text{ V}$	5.5	11177	
$V_{GS(th)}$	Threshold Voltage	0.9	V		

Device Information⁽¹⁾

DEVICE	QTY	MEDIA	PACKAGE	SHIP
CSD87313DMS	2500	13-Inch Reel	SON	Tape
CSD87313DMST	250	7-Inch Reel	3.30-mm × 3.30-mm Plastic Package	and Reel

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Absolute Maximum Ratings

		-	
T _A = 2	5°C unless otherwise stated	VALUE	UNIT
$V_{\rm S1S2}$	Source1-to-Source2 Voltage	30	V
V_{GS}	Gate-to-Source Voltage ⁽¹⁾	±10	V
I _{S1S2}	Continuous Source Current ⁽²⁾	17	Α
I _{SM}	Pulsed Source Current, T _A = 25°C ⁽²⁾⁽³⁾	120	Α
ר	Power Dissipation ⁽²⁾	2.7	W
P_D	Power Dissipation ⁽⁴⁾	1	VV
T _{J,} T _{stg}	Operating Junction, Storage Temperature	-55 to 150	°C
E _{AS}	Avalanche Energy, Single Pulse, $I_D = 37 \text{ A}, L = 0.1 \text{ mH}, R_G = 25 \Omega$	67	mJ

- (1) V_{G1S1} should not exceed ±10 V and V_{G2S2} should not exceed ±10 V.
- (2) Typical $R_{\theta JA} = 45^{\circ}\text{C/W}$ when mounted on a 1-in² (6.45-cm²), 2-oz (0.071-mm) thick Cu pad on a 0.06-in (1.52-mm) thick
- (3) Duty cycle ≤ 2%, pulse duration ≤ 300 μs.
- (4) Typical $R_{\theta JA} = 125^{\circ}C/W$ on a minimum 2-oz Cu pad.

Gate Charge

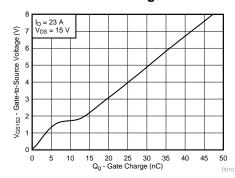




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4 Revision History

DATE	REVISION	NOTES
April 2017	*	Initial release.

Product Folder Links: CSD87313DMS

John Documentation Feedback



5 Specifications

5.1 Electrical Characteristics

 $T_A = 25^{\circ}C$ (unless otherwise stated)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
STATIC C	HARACTERISTICS					
I _{S1S2}	Source1-to-Source2 leakage current	V _{G1S1} = 0 V, V _{G2S2} = 0 V, V _{S1S2} = 24 V			1	μΑ
I _{GSS}	Gate-to-source leakage current	V _{S1S2} = 0 V, V _{GS} = 10 V			100	nA
V _{GS(th)}	Gate-to-source threshold voltage	V _{S1S2} = V _{GS} , I _{S1S2} = 250 μA	0.6	0.9	1.2	V
_	0 11 0 0 11	V _{GS} = 2.5 V, I _{S1S2} = 20 A		6.7	9.6	
R _{S1S2(on)}	Source1-to-Source2 on resistance	V _{GS} = 4.5 V, I _{S1S2} = 23 A		4.6	5.5	mΩ
9 _{fs}	Transconductance	V _{S1S2} = 3 V, I _{S1S2} = 23 A		149		S
DYNAMIC	CHARACTERISTICS ⁽¹⁾				•	
C _{ISS}	Input capacitance			3300	4290	pF
Coss	Output capacitance	$V_{GS} = 0 \text{ V}, V_{S1S2} = 15 \text{ V}, f = 1 \text{ MHz}$		281	365	pF
C _{RSS}	Reverse transfer capacitance			154	200	pF
Qg	Gate charge total (4.5 V)			28		nC
Q _{gd}	Gate charge gate-to-drain	V _{S1S2} = 15 V, I _{S1S2} = 23 A V _{G1S1} = 4.5 V, V _{G2S2} = 0 V		6.0		nC
Q _{gs}	Gate charge gate-to-source	VG1S1 = 4.5 V, VG2S2 = 0 V		6.3		nC
Q _{g(th)}	Gate charge at V _{th}			3.2		nC
t _{d(on)}	Turnon delay time			9		ns
t _r	Rise time	V _{S1S2} = 15 V, I _{S1S2} = 23 A		27		ns
t _{d(off)}	Turnoff delay time	$V_{GS} = 4.5 \text{ V}, R_{GEN} = 0 \Omega$		41		ns
t _f	Fall time			13		ns
DIODE CH	IARACTERISTICS				,	
I _{fss}	Maximum continuous Source1-to-Source2 diode forward current ⁽²⁾	V _{G1S1} = 0 V, V _{G2S2} = 4.5 V			2	А
V _{fss}	Source1-to-Source2 diode forward voltage	$V_{G1S1} = 0 \text{ V}, V_{G2S2} = 4.5 \text{ V}, I_{fss} = 23 \text{ A}$		0.8	1.0	V

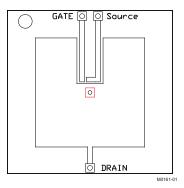
- (1) Dynamic characteristic measurements are for a single FET.
- (2) Typical $R_{\theta JA} = 125$ °C/W on a minimum 2-oz Cu pad.

5.2 Thermal Information

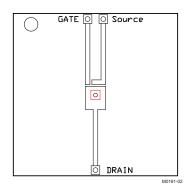
 $T_A = 25$ °C (unless otherwise stated)

	THERMAL METRIC		UNIT
$R_{\theta JA}$	Junction-to-case thermal resistance ⁽¹⁾	125	°C/W
$R_{\theta JA}$	Junction-to-ambient thermal resistance ⁽¹⁾⁽²⁾	45	°C/W

- (1) Device mounted on minimum 2-oz (0.071-mm) thick Cu.
- (2) Device mounted on FR4 material with 1-in² (6.45-cm²), 2-oz (0.071-mm) thick Cu.



 $R_{\theta JA} = 45^{\circ}\text{C/W}$ when mounted on 1 in² (6.45 cm²) of 2-oz (0.071-mm) thick Cu.



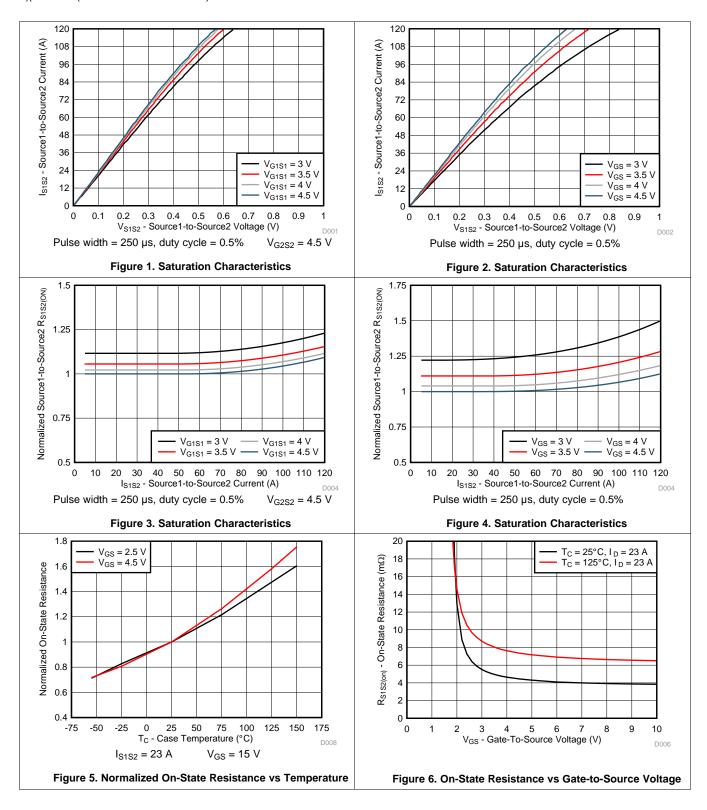
 $R_{\theta JA} = 125^{\circ} C/W$ when mounted on a minimum pad area of 2-oz (0.071-mm) thick Cu.

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TEXAS INSTRUMENTS

5.3 Typical MOSFET Characteristics

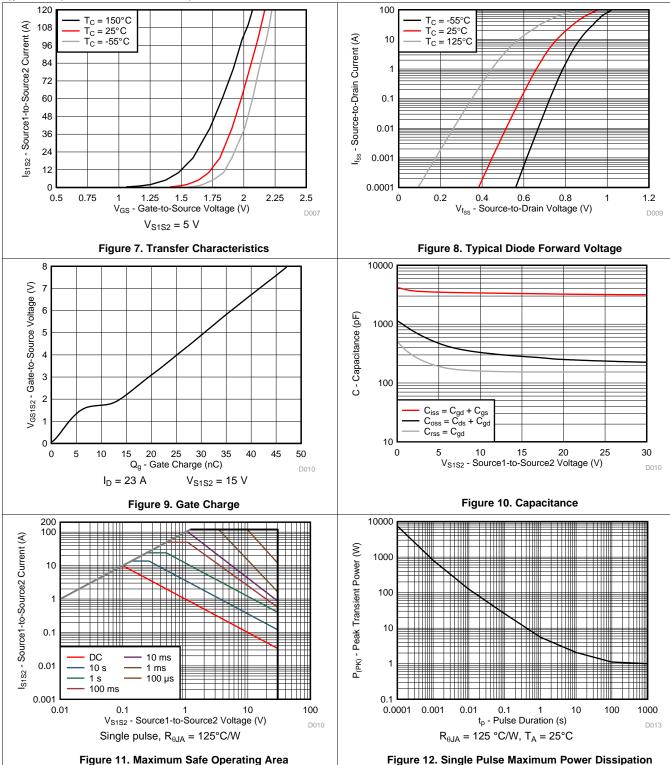
 $T_A = 25$ °C (unless otherwise stated)





Typical MOSFET Characteristics (continued)

 $T_A = 25$ °C (unless otherwise stated)

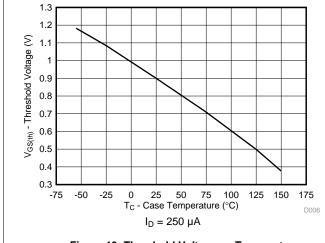


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TEXAS INSTRUMENTS

Typical MOSFET Characteristics (continued)

 $T_A = 25$ °C (unless otherwise stated)



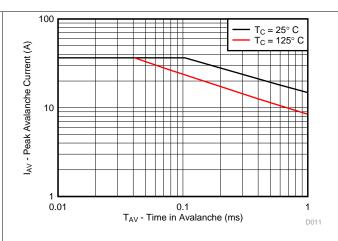


Figure 13. Threshold Voltage vs Temperature

Figure 14. Single Pulse Unclamped Inductive Switching

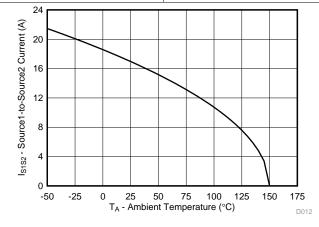


Figure 15. Maximum Source1-to-Source2 Current vs Temperature

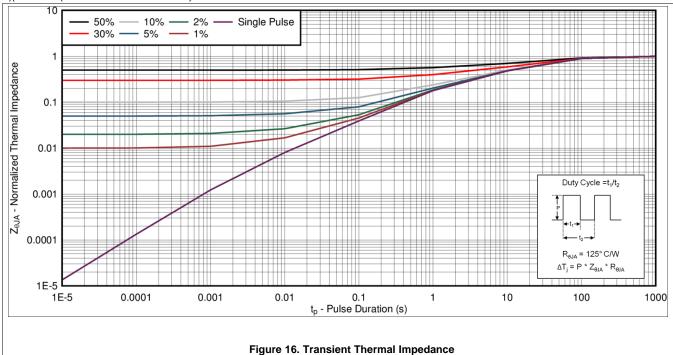
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Typical MOSFET Characteristics (continued)

 $T_A = 25$ °C (unless otherwise stated)



TEXAS INSTRUMENTS

6 Device and Documentation Support

6.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

6.2 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Online Community TI's Engineer-to-Engineer (E2E) Community. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

6.3 Trademarks

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6.4 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

6.5 Glossary

SLYZ022 — TI Glossary.

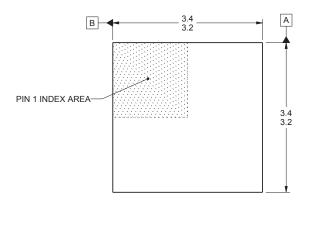
This glossary lists and explains terms, acronyms, and definitions.



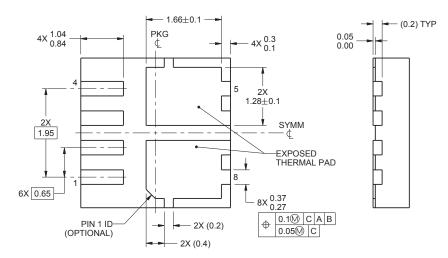
Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

7.1 DMS Package Dimensions







4222980/A 05/2016

- (1) All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- (2) This drawing is subject to change without notice.
- (3) The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

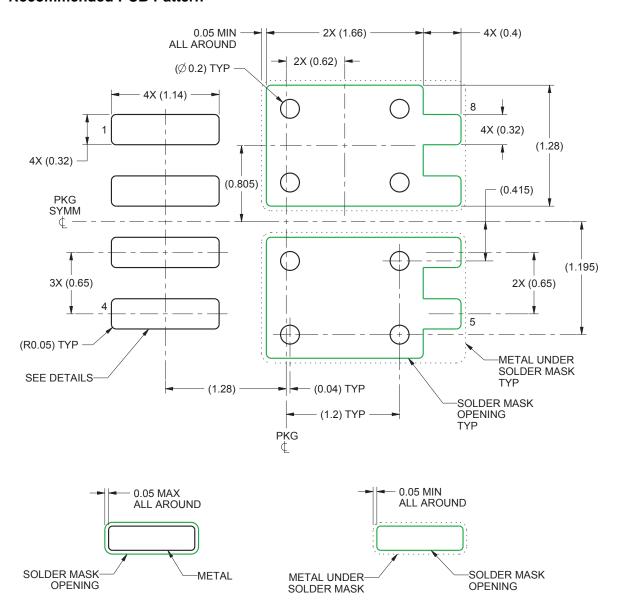
Table 1. Pin Configuration Table

POSITION	DESIGNATION	POSITION	DESIGNATION		
1	Gate 1	5	Source 2		
2	Drain	6	Source 2		
3	Drain	7	Source 1		
4	Gate 2	8	Source 1		

Product Folder Links: CSD87313DMS

TEXAS INSTRUMENTS

7.2 Recommended PCB Pattern



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SOLDER MASK

DEFINED

- This package is designed to be soldered to a thermal pad on the board. For more information, see QFN/SON PCB Attachment (SLUA271).
- (2) Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

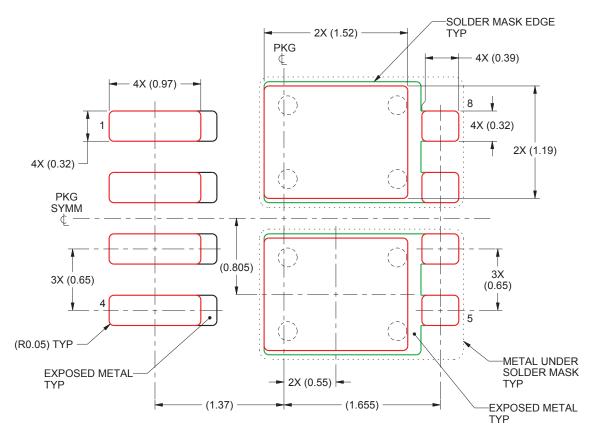
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NON-SOLDER MASK

DEFINED



7.3 Recommended Stencil Opening



(1) Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



PACKAGE OPTION ADDENDUM

19-Apr-2017

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
CSD87313DMS	ACTIVE	WSON	DMS	8	2500	Pb-Free (RoHS Exempt)	CU SN	Level-1-260C-UNLIM	-55 to 150	CSD87313	Samples
CSD87313DMST	ACTIVE	WSON	DMS	8	250	Pb-Free (RoHS Exempt)	CU SN	Level-1-260C-UNLIM	-55 to 150	CSD87313	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

19-Apr-2017

n no event shall TI's liability arising out of such information	on exceed the total purchase price of the TI part(s) at issue	in this document sold by TI to Customer on an annual basis.
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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

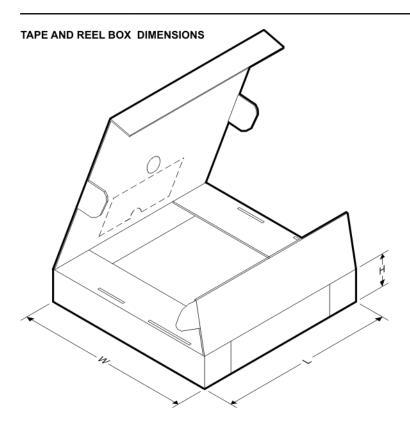
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CSD87313DMS	WSON	DMS	8	2500	330.0	12.4	3.6	3.6	1.2	8.0	12.0	Q1
CSD87313DMST	WSON	DMS	8	250	178.0	12.4	3.6	3.6	1.2	8.0	12.0	Q1

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CSD87313DMS	WSON	DMS	8	2500	333.2	345.9	28.6
CSD87313DMST	WSON	DMS	8	250	210.0	210.0	52.0

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